

## **One-Line ESD Protection** Low Capacitance Bi-direction TVS

#### **General Description**

AFE0582 are designed by bi-direction TVS diode, to protect high speed data interfaces. This product has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by ESD (electrostatic discharge), CDE (Cable Discharge Events), and EFT (electrical fast transients). The TVS diode prevents over-voltage on the power line, protecting any downstream components. The low capacitance configuration allows the user to protect high-speed data or transmission lines. This device is optimized for ESD protection of portable electronics. They may be used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 (±15kV air, ±8kV contact discharge).

#### **Features**

- Transient protection for high-speed data lines to IEC 61000-4-2 (ESD) ±15kV (air), ±8kV (contact) IEC 61000-4-4 (EFT) 40A (5/50ns)
- Small package saves board space
- Protects up to four I/O lines & power line
- Low capacitance (<3pF) for high-speed interfaces
- Low leakage current and clamping voltage
- Low operating voltage: 5.0V
- Solid-state silicon-avalanche technology

### **Application**

- USB 2.0 Power and Data Line Protection
- Monitors and Flat Panel Displays
- Digital Visual Interface (DVI)
- 10/100/1000 Ethernet
- Notebook Computer
- SIM Ports
- ATM Interface
- IEEE 1394 Firewire Ports
- Cellular Handsets & Accessories
- Portable Instrumentation
- **Digital Cameras**
- MP3 Players
- Video Graphics Cards

#### Pin Description (FBP-02C)



## Schematic & PIN Configuration(FBP-02C)



#### **Ordering Information**

Part Ordering No.	Part Marking	Package	Unit	Quantity
AFE0582BP02RG	8	FBP-02C	Tape & Reel	10000 EA

AFE0582BP02RG: 7" Tape & Reel; Pb- Free; Halogen- Free

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#### **ABSOULTE MAXIMUM RATINGS**

(T<sub>A</sub>=25°C Unless otherwise noted)

Parameter	Symbol	Typical	Unit
Peak Pulse Power ( t <sub>p</sub> = 8/20 μs )	P <sub>pk</sub>	100	W
Maximum Peak Pulse Current ( t <sub>p</sub> = 8/20 μs )	l <sub>PP</sub>	4	А
ESD per IEC 61000 – 4 – 2 (Air )	V <sub>PP</sub>	±15	KV
ESD per IEC 61000 – 4 – 2 (Contact )	V <sub>PP</sub>	±8	KV
Operating Junction Temperature	TJ	-55 ~ 125	$^{\circ}\!\mathbb{C}$
Storage Temperature Range	Tstg	-55 ~ 150	$^{\circ}\!\mathbb{C}$
Lead Soldering Temperature	T∟	260 ( 10sec )	$^{\circ}$ C

#### **ELECTRICAL CHARACTERISTICS**

(Ta=25°C Unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit
Reverse Stand – Off Voltage	V <sub>RWM</sub>	Pin 1 to 2 or Pin 2 to 1			5	V
Reverse Breakdown Voltage	V <sub>BR</sub>	It = 1mA Pin 1 to 2 or Pin 2 to 1	6			٧
Reverse Leakage Current	IR	V <sub>RWM</sub> = 5V , T=25°C Pin 1 to 2 or Pin 2 to 1		0.5	1.0	μA
Clamping Voltage	Vc	I <sub>PP</sub> = 1A , tp = 8/20 μs Pin 1 to 2 or 2 to 1			13	٧
Clamping Voltage	Vc	I <sub>PP</sub> = 4A , tp = 8/20 μs Pin 1 to 2 or 2 to 1			15	٧
Junction Capacitance	Cj	V <sub>R</sub> = 0V , f = 1MHz		2	3	pF

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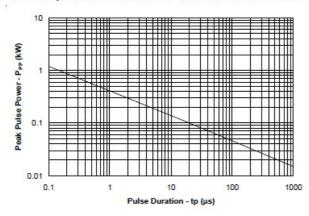
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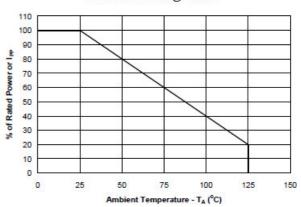
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## **Typical Characteristics**

#### Non-Repetitive Peak Pulse Power vs. Pulse Time



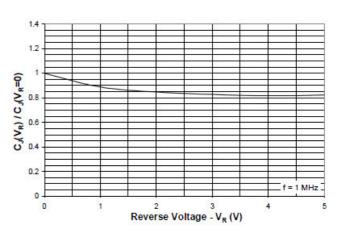
## **Power Derating Curve**



#### Clamping Voltage vs. Peak Pulse Current

# 24 22 20 18 3 16 4 12 10 10 10 8 6 4 10 Parameters: tr = 8µs td = 20µs 0 1 2 3 4 5 Peak Pulse Current - I<sub>pp</sub> (A)

#### Normalized Capacitance vs. Reverse Voltage



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## **One-Line ESD Protection** Low Capacitance Bi-direction TVS

#### **Application Information**

#### **Device Connection Options**

These TVS diodes are designed to protect one data, I/O, or power supply line. The device is bi-directional and may be used on lines where the signal polarity can go above and below ground.

#### Circuit Board Layout Recommendations for Suppression of ESD.

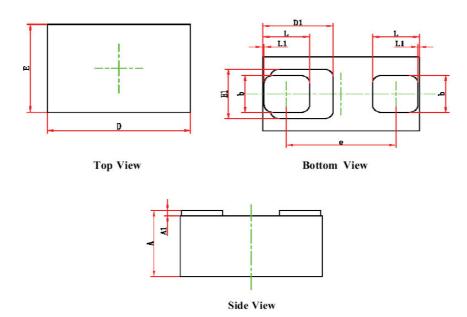
Good circuit board layout is critical for the suppression of ESD induced transients. The following guidelines are recommended:

- Place the TVS near the input terminals or connectors to restrict transient coupling.
- Minimize the path length between the TVS and the protected line.
- Minimize all conductive loops including power and ground loops.
- The ESD transient return path to ground should be kept as short as possible.
- Never run critical signals near board edges.
- Use ground planes whenever possible.



## One-Line ESD Protection Low Capacitance Bi-direction TVS

## Package Information (FBP-02C)



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	0.450	0.550	0.018	0.022	
A1	0.010	0.070	0.000	0.003	
D	0.95	1.050	0.037	0.011	
Е	0.550	0.650	0.022	0.026	
D1	0.450REF		0.018REF		
E1	0.400REF		0.016REF		
b	0.275	0.325		0.013	
e	0.675	0.725		0.029	
L	0.275	0.325		0.013	
L1	0.010REF		0.000REF		

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